

TOSHIBA Field Effect Transistor Silicon P Channel MOS Type

SSM3J01F

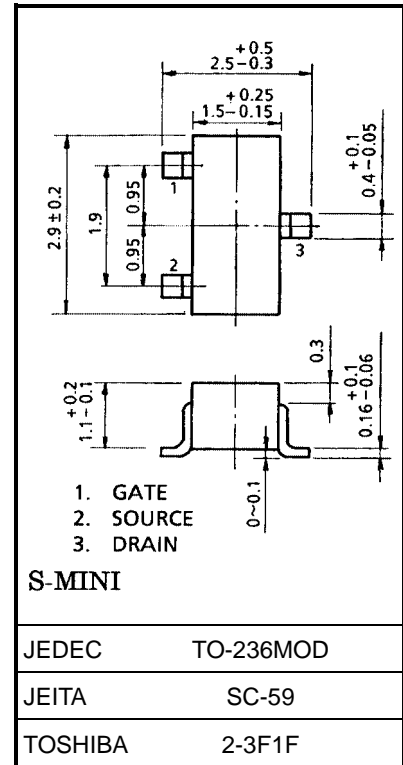
High Speed Switching Applications

- Small package
- Low on resistance: $R_{on} = 0.4 \Omega$ (max) ($V_{GS} = -4 V$)
: $R_{on} = 0.6 \Omega$ (max) ($V_{GS} = -2.5 V$)
- Low gate threshold voltage

Maximum Ratings ($T_a = 25^\circ C$)

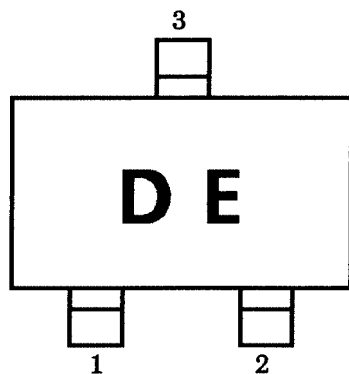
Characteristics		Symbol	Rating	Unit
Drain-source voltage		V_{DS}	-30	V
Gate-source voltage		V_{GSS}	± 10	V
Drain current	DC	I_D	-700	mA
	Pulse	I_{DP}	-1400	
Drain power dissipation ($T_a = 25^\circ C$)		P_D	200	mW
Channel temperature		T_{ch}	150	$^\circ C$
Storage temperature range		T_{stg}	-55~150	$^\circ C$

Unit: mm

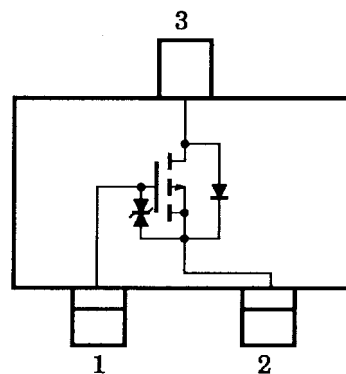


Weight: 0.012 g (typ.)

Marking



Equivalent Circuit



Handling Precaution

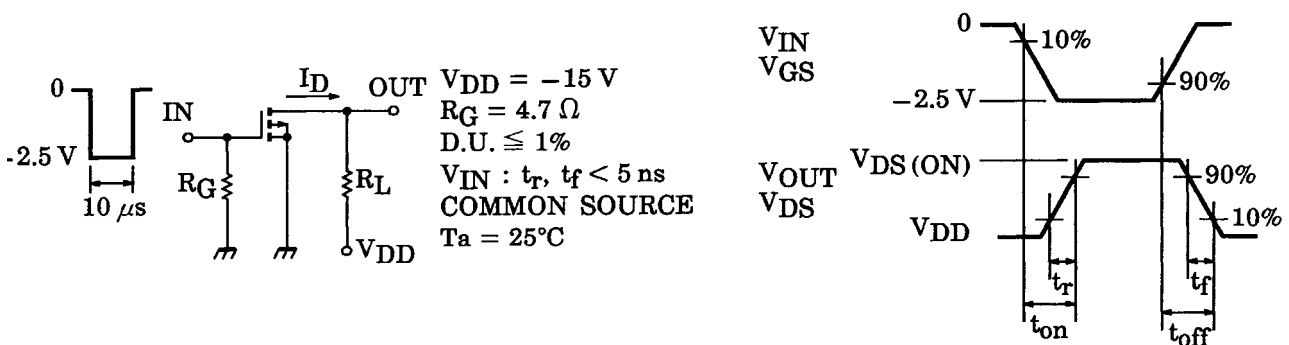
When handling individual devices (which are not yet mounting on a circuit board), be sure that the environment is protected against electrostatic electricity. Operators should wear anti-static clothing, and containers and other objects that come into direct contact with devices should be made of anti-static materials.

Electrical Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Gate leakage current	I_{GSS}	$V_{GS} = \pm 10\text{ V}, V_{DS} = 0$	—	—	± 1	μA
Drain-source breakdown voltage	$V_{(BR)DSS}$	$I_D = -1\text{ mA}, V_{GS} = 0$	-30	—	—	V
Drain cut-off current	I_{DSS}	$V_{DS} = -30\text{ V}, V_{GS} = 0$	—	—	-1	μA
Gate threshold voltage	V_{th}	$V_{DS} = -3\text{ V}, I_D = -0.1\text{ mA}$	-0.6	—	-1.1	V
Forward transfer admittance	$ Y_{fs} $ (Note)	$V_{DS} = -3\text{ V}, I_D = -0.35\text{ A}$	1.0	—	—	S
Drain-source ON resistance	$R_{DS(ON)}$ (Note)	$I_D = -0.35\text{ A}, V_{GS} = -4\text{ V}$	—	0.3	0.4	Ω
		$I_D = -0.35\text{ A}, V_{GS} = -2.5\text{ V}$	—	0.4	0.6	
Input capacitance	C_{iss}	$V_{DS} = -10\text{ V}, V_{GS} = 0, f = 1\text{ MHz}$	—	240	—	pF
Reverse transfer capacitance	C_{rss}	$V_{DS} = -10\text{ V}, V_{GS} = 0, f = 1\text{ MHz}$	—	24	—	pF
Output capacitance	C_{oss}	$V_{DS} = -10\text{ V}, V_{GS} = 0, f = 1\text{ MHz}$	—	94	—	pF
Switching time	Turn-on time	$V_{DD} = -15\text{ V}, I_D = -0.3\text{ A},$ $V_{GS} = 0 \sim -2.5\text{ V}, R_G = 4.7\ \Omega$	—	36	—	ns
	Turn-off time		—	37	—	

Note: Pulse test

Switching Time Test Circuit



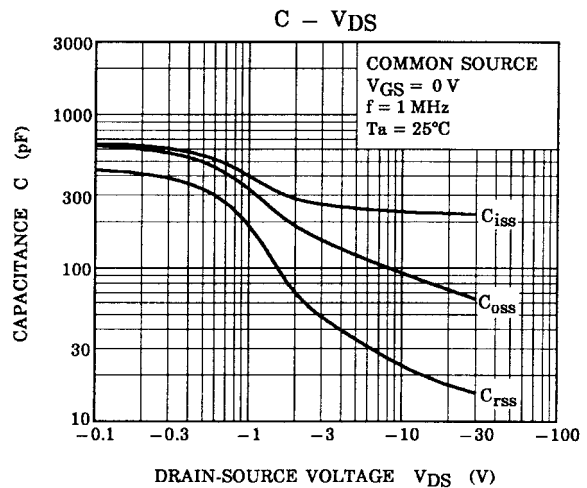
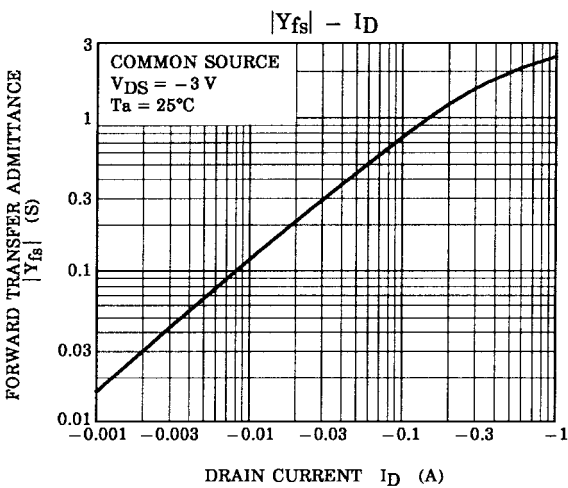
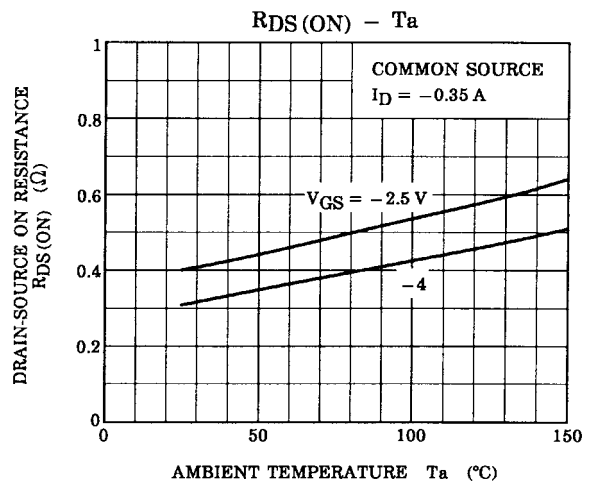
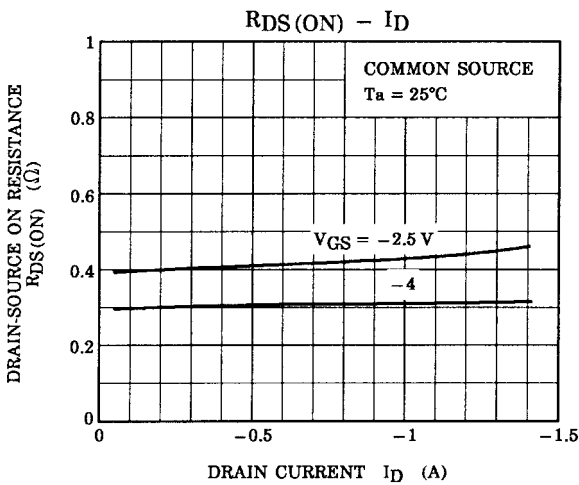
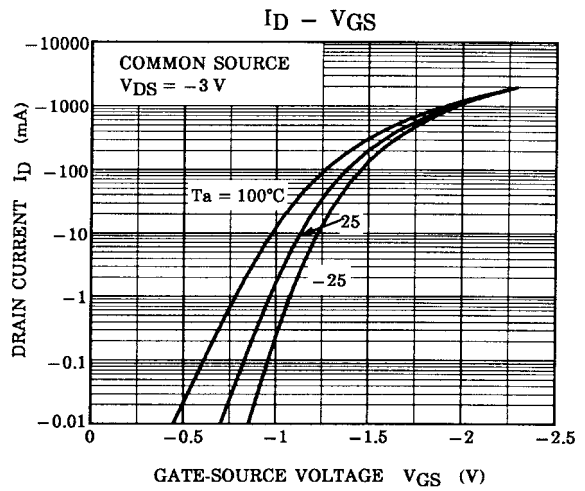
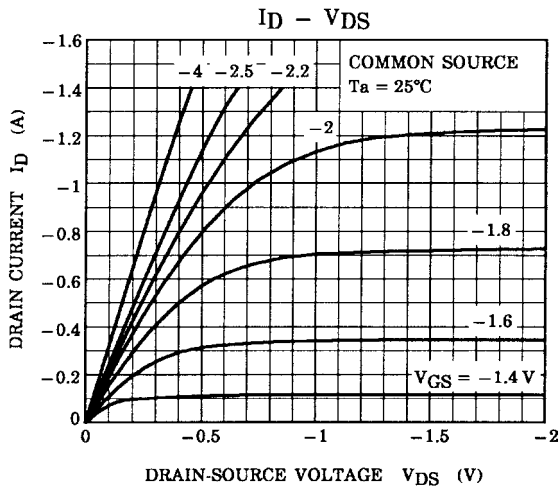
Precaution

V_{th} can be expressed as voltage between gate and source when low operating current value is $I_D = -100\ \mu\text{A}$ for this product. For normal switching operation, $V_{GS(ON)}$ requires higher voltage than V_{th} and $V_{GS(off)}$ requires lower voltage than V_{th} .

(Relationship can be established as follows: $V_{GS(off)} < V_{th} < V_{GS(ON)}$)

Please take this into consideration for using the device.

V_{GS} recommended voltage of -2.5 V or higher to turn on this product.



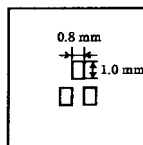
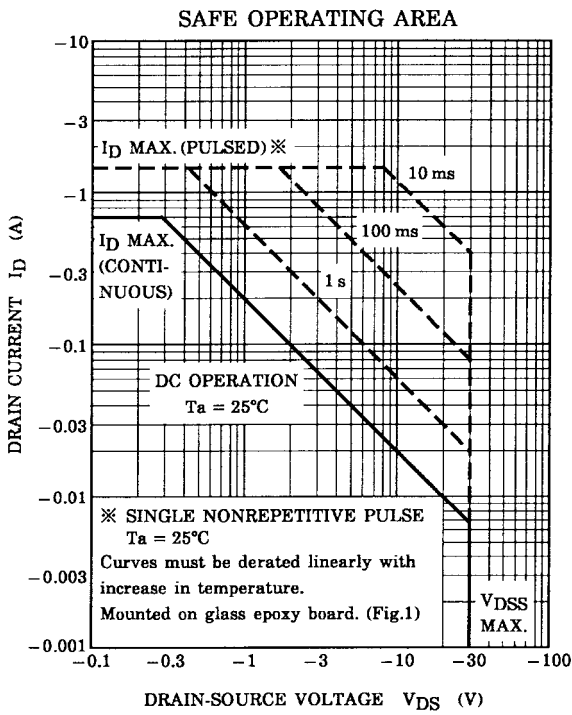
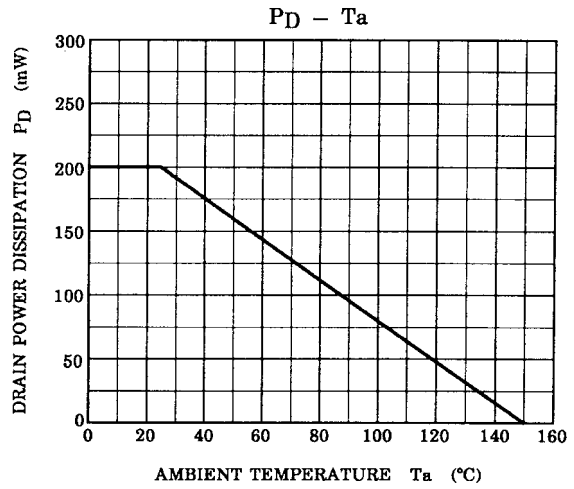
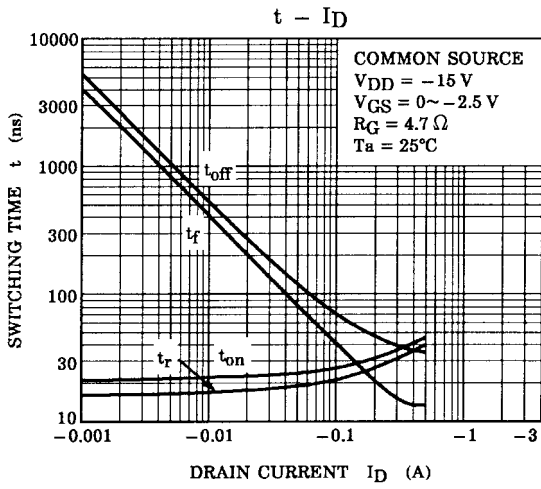


Figure 1 25.4 mm × 25.4 mm × 1.6 t (a Cu pad of 0.8 mm² area)

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